NSN 5961-01-323-8635

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-323-8635 **Inclosure Material:** Ceramic or glass **Overall Length:** 1.375 inches **Terminal Length:** 1.250 inches **Overall Height:** 0.375 inches **Overall Width:** 0.250 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 8000.0 reverse voltage, peak **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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